

# **AXIAL LEADED SILICON RECTIFIER DIODES**

VOLTAGE RANGE: 400V CURRENT: 1.0 A

#### **Features**

Diffused Junction

Low Forward Voltage Drop

High Current Capability

High Reliability

High Surge Current Capability

### **Mechanical Data**

Case: DO-15

Terminals: Plated Leads Solderable per

MIL-STD-202, Method 208

Polarity: Cathode Band

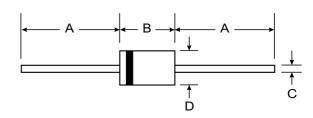
Weight: 0.40 grams (approx.)

Mounting Position: Any

Marking: Type Number







DO-15			
Dim	Min	Max	
Α	25.40	_	
В	5.50	7.62	
С	0.686	0.889	
D	2.60	3.60	
All Dimensions in mm			

## Maximum Ratings and Electrical Characteristics $T_A = 25$ °C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	1S1829	Unit
Maximum Recurrent Peak Reverse Voltage	VRRM	400	V
Maximum Average Forward Current	<b>I</b> F(AV)	1.0	А
$0.375"(9.5mm)$ Lead Length Ta = $50  ^{\circ}$ C	IF(AV)		
Peak Forward Surge Current, 8.3ms Single half sine wave	IFSM	45	А
Superimposed on rated load (JEDEC Method)	ILOM		
Maximum Peak Forward Voltage at IF = 1.5 Amps.	VF	1.2	V
Repetitive Peak Reverse	I <sub>RRM(1)</sub>	10	μA
Current Tj = 150 °C	IRRM(2)	400	μΑ
Storage Temperature Range	Tstg	- 40 to + 150	С
Junction Temperature Range	TJ	- 40 to + 150	°C
Thermal Resistance (Junction to Ambient) DC	Rth(j-a)	100	°C/W

### Notes:

- (1) Reverse Recovery Test Conditions : IF = 0.5 A, IR = 1.0 A, Irr = 0.25 A.
- ( 2 )  $\,$  Measured at 1.0 MHz and applied reverse voltage of 4.0  $\,$  Vpc  $\,$



